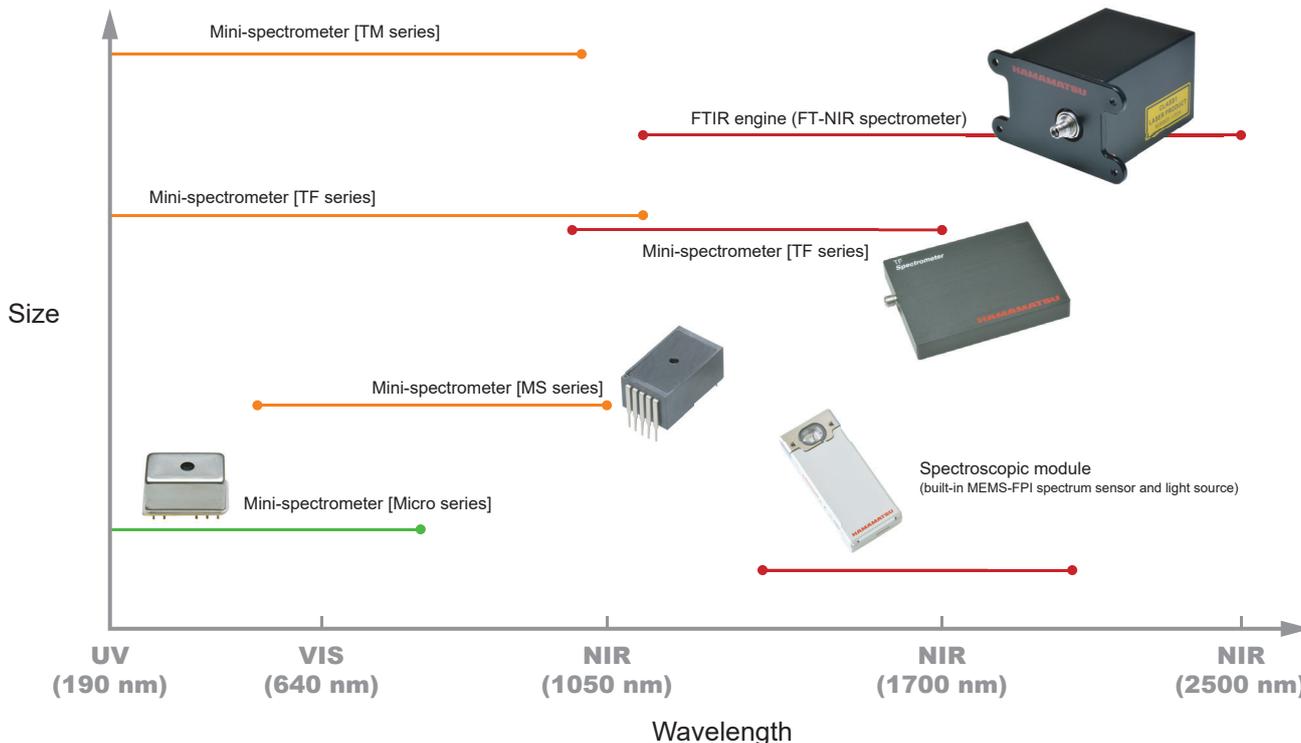


Spectrum sensors / Spectrometers for portable simple analysis

Hamamatsu offers spectrum sensors and spectrometers that enable real-time measurements in the field. They can be installed in a variety of equipment, including environmental measurement equipment, color measurement equipment, and production lines.

Product map of Hamamatsu's Spectrum sensors and Spectrometers for portable simple analysis



Application examples



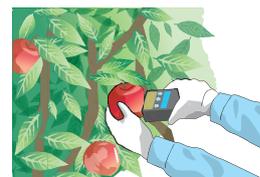
Water analysis



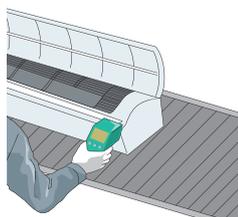
Light monitor (Plant factories, etc.)



Soil analysis (Field)



Farm product test (Sugar, Chlorophyll, etc.)



Plastic sorting (Recycle plant, etc.)



Textile sorting (Home laundry, Used clothing recycling, etc.)



Material test (Incoming inspection)



Color analysis (Paint state)

Conventional analysis
Sampling → Pre-processing → Analysis at lab.

On-site real-time measurement
- Pre-processing unnecessary - Immediate result

FTIR engine (FT-NIR spectrometer)

C15511-01



Compact spectrometer module with built-in Michelson optical interferometer

The C15511-01 Fourier transform infrared spectrometer (FTIR) engine is compact enough to carry in just one hand. A Michelson optical interferometer and control circuit are built into a palm-sized enclosure. Spectrum and absorbance can be measured by connecting a PC via USB. It can be applied to real-time measurement performed on site without bringing the measurement sample into the analysis room as well as continuous monitoring.

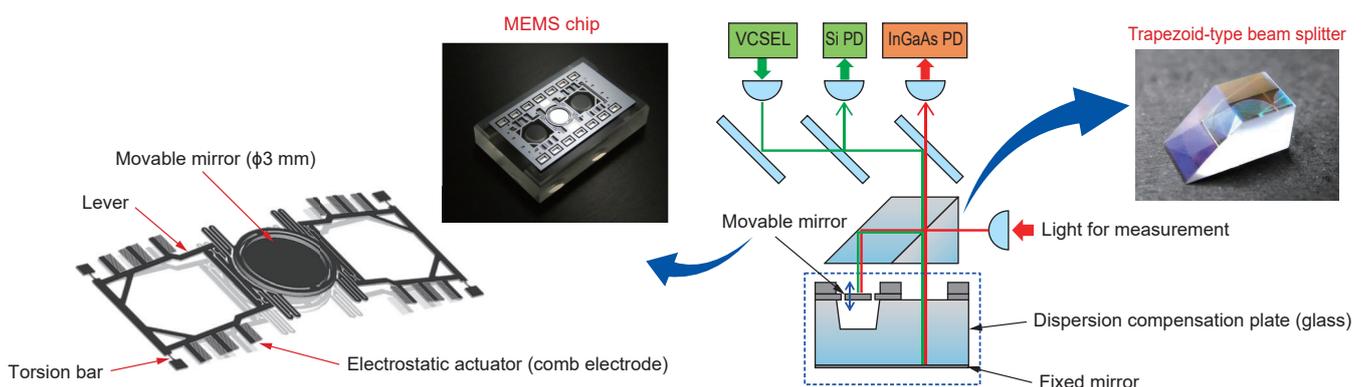
Specifications (Ta=25 °C, unless otherwise noted)

Parameter	Min.	Typ.	Max.	Unit
Spectral response range	1100 to 2500			nm
Spectral resolution (FWHM)	-	5.7	8	nm
Wavelength reproducibility	-	-	+0.5	nm
Wavelength temperature dependence	-0.06	-	+0.06	nm/°C
Signal-to-noise ratio	10000	-	-	-
Dimensions (W × D × H)	57 × 76 × 49 (excluding protrusions)			mm
Weight	Approx. 300			g
Optical interferometer	Michelson interferometer (with a built-in $\phi 3$ mm movable mirror)			-
Photodetector	InGaAs PIN photodiode			-
Light input method	Optical fiber input type (with SMA connector)			-
Interface	USB 2.0			-
A/D conversion	-	16	-	bit
Drive frequency	225	275	325	Hz
USB bus power current consumption	-	450	500	mA
Storage temperature	-20 to +70			°C
Operating temperature	+5 to +50			°C

Structure

The optical interferometer has a built-in light input section, beam splitter, fixed mirror, movable mirror ($\phi 3$ mm), and photodetector. The photodetector acquires light intensity signals that vary depending on the position of the movable mirror. The optical spectrum is obtained by processing (Fourier transform) these light intensity signals.

The FTIR engine has a built-in semiconductor laser (VCSEL: vertical cavity surface emitting laser) for monitoring the movable mirror position, which allows spectrum measurement with high wavelength accuracy.



Spectroscopic modules

C17552, C17553, C17554



Compact module with MEMS-FPI spectrum sensor and light source

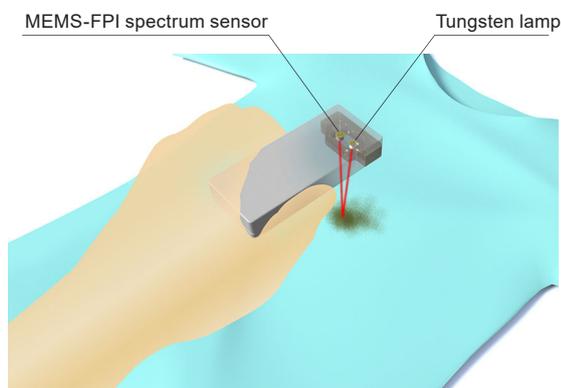
This compact module has a built-in light source, control circuit, and MEMS-FPI spectrum sensor consisting of an InGaAs PIN photodiode and MEMS-FPI (Fabry-Perot Interferometer) tunable filter which can vary its transmission wavelength by changing the applied voltage. Spectrum and absorbance can be measured by connecting a PC via USB.

Specifications (Typ. $T_a=25\text{ }^\circ\text{C}$, unless otherwise noted)

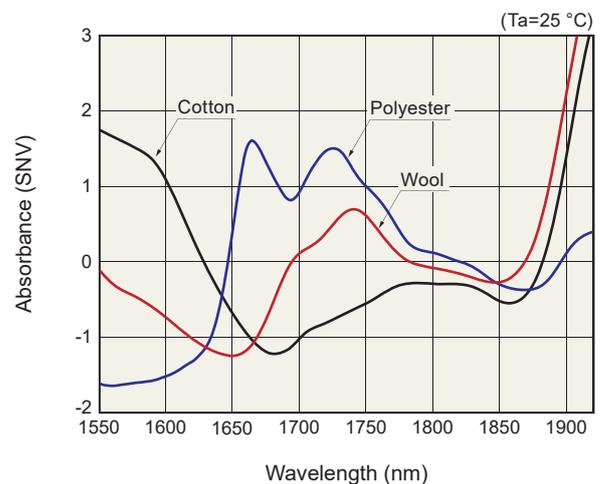
Parameter	C17552	C17553	C17554	Unit
Light source	Tungsten lamp			-
Interface	USB 2.0 micro-B			-
Dimensions (W × D × H)	32 × 74 × 16			mm
Weight	63			g
Operating temperature	-5 to +50			$^\circ\text{C}$
Storage temperature	-20 to +70			$^\circ\text{C}$
Spectral response range	1350 to 1650	1550 to 1920	1750 to 2150	nm
Spectral resolution (FWHM)	18 max.	21 max.	22 max.	nm
Wavelength reproducibility	± 2 typ.			nm
Wavelength temperature dependence	-0.1 to +0.1			nm/ $^\circ\text{C}$

Measurement example

Measured the reflection spectrum of textiles (cotton, polyester, wool) using this module.



Absorbance spectrum of textiles



Mini-spectrometers [TF series]

C13555MA, C13053MA, C14486GA



Thin type, different wavelength types available

These mini-spectrometers are a thin type that has achieved 12 mm thickness while maintaining high performance. At the C13555MA and C13053MA, the incorporation of a high-sensitivity CMOS image sensor has achieved high sensitivity equivalent to that of a CCD and low power consumption.

The C14486GA is near infrared type mounted with InGaAs linear image sensor.

Specifications (Typ. Ta=25 °C, unless otherwise noted)

Parameter	C13555MA	C13053MA	C14486GA	Unit
Product				-
Type	High sensitivity		For near NIR	-
Spectral response range	340 to 830	500 to 1100	950 to 1700	nm
Spectral resolution (FWHM)	2.3 typ., 3.0 max.	2.5 typ., 3.5 max.	5.0 typ., 7.0 max.	nm
Wavelength reproducibility	-0.2 to +0.2	-0.4 to +0.4	-0.4 to +0.4	nm
Wavelength temperature dependence	-0.04 to +0.04		-0.05 to +0.05	nm/°C
Spectral stray light	-33 max.		-33 max.	dB
A/D conversion	16			bit
Integration time	11 to 100000		1 to 100000	μs
Interface	USB 2.0			-
USB bus power current consumption	250 max.			mA
Driving external power supply	Not needed			V
Dimensions (W × D × H)	80 × 60 × 12			mm
Weight	90	88		g
Image sensor	High-sensitivity CMOS linear image sensor		InGaAs linear image sensor	-
Number of pixels	512		256	Pixels
Slit (H × V)	25 × 250		25 × 250	μm
NA	0.22		0.22	-
Connector for optical fiber	SMA905D			-
Operating temperature	+5 to +50			°C
Storage temperature	-20 to +70			°C
Trigger compatible	Software trigger External trigger			-

Note: The C13054MA and C14214MA for Raman spectroscopy are also available.

Mini-spectrometers [Micro / MS series]

C16767MA, C12666MA, C12880MA, C11708MA



Finger-tip sized, ultra-compact spectrometer head

Based on an advanced MOEMS technology, a thumb-sized ultra-compact spectrometer heads have been achieved by combining an input-slit-integrated CMOS image sensor and grating formed through nanoimprint on a convex lens. As they employ an easily mountable package, you can use them as though they were sensors.

Specifications (Typ. Ta=25 °C, unless otherwise noted)

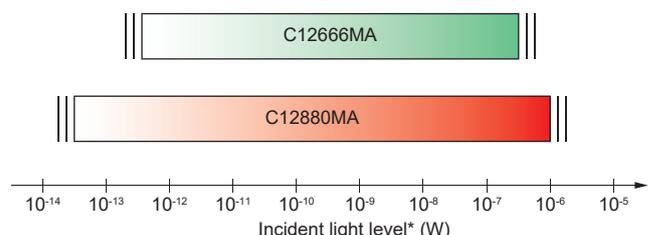
Parameter	Micro series			MS series	Unit
	C16767MA	C12880MA	C12666MA	C11708MA	
Product					-
Type	Spectrometer head UV high-sensitivity	Spectrometer head High-sensitivity	Spectrometer head Wide dynamic range	Spectrometer head For NIR	-
Spectral response range	190 to 440	340 to 850	340 to 780	640 to 1050	nm
Spectral resolution (FWHM)	8 max.	15 max.	15 max.	20 max.	nm
Wavelength reproducibility	-0.5 to +0.5	-0.5 to +0.5	-0.5 to +0.5	-0.5 to +0.5	mm
Wavelength temperature dependence	-0.07 to +0.07	-0.1 to +0.1	-0.1 to +0.1	-0.05 to +0.05	nm/°C
Spectral stray light	-25 max.	-25 max.	-25 max.	-25 max.	dB
Dimensions (W × D × H)	20.1 × 12.5 × 10.1	20.1 × 12.5 × 10.1	20.1 × 12.5 × 10.1	27.6 × 16.8 × 13	mm
Weight	5	5	5	9	g
Image sensor	High-sensitivity CMOS linear image sensor	High-sensitivity CMOS linear image sensor	CMOS linear image sensor	CMOS linear image sensor	-
Number of pixels	288	288	256	256	Pixels
Slit (H × V)	50 × 500	50 × 500	50 × 750	75 × 750	μm
NA	0.22	0.22	0.22	0.22	-
Operating temperature	+5 to +50	+5 to +50	+5 to +50	+5 to +50	°C
Storage temperature	-20 to +70	-20 to +70	-20 to +70	-20 to +70	°C
Evaluation circuit (sold separately)	C13016	C13016	C14465-10	C14465	-

Note: We also provide the C12880MA-20 and C12666MA-20, which are identical to the C12880MA and C12666MA except that it has an SMA connector.

Measurable incident light level

The CMOS image sensor built into the C12666MA has a large saturation charge, and that built into the C12880MA has a large charge-to-voltage conversion gain.

To perform high S/N measurement, the C12666MA is recommended when the incident light level is high and the C12880MA when the level is low.



* Input spot diameter: 800 μm (λ=550 nm: C12666MA, λ=600 nm: C12880MA)
 The measurable light level is calculated from the settable integration time.
 The settable integration time is different between the C12666MA and C12880MA.
 The S/N during measurement is not taken into account.

Main Products

Opto-semiconductors

- Si photodiodes
 - APD
 - MPPC®
 - Photo IC
 - Image sensors
 - PSD
 - Infrared detectors
 - LED
 - Optical communication devices
 - Automotive devices
 - X-ray flat panel sensors
 - MEMS devices
 - Mini-spectrometers
 - Opto-semiconductor modules
-

Electron Tubes

- Photomultiplier tubes
 - Photomultiplier tube modules
 - Microchannel plates
 - Image intensifiers
 - Xenon lamps / Mercury-xenon lamps
 - Deuterium lamps
 - Light source applied products
 - Laser applied products
 - Microfocus X-ray sources
 - X-ray imaging devices
-

Imaging and Processing Systems

- Scientific cameras
 - Spectroscopic and optical measurement systems
 - Ultrafast photometry systems
 - Life science systems
 - Medical systems
 - Non-destructive inspection products
 - Semiconductor manufacturing support systems
 - Material research systems
-

Laser Products

- Single chip laser diodes
 - Laser diode bar modules
 - Quantum cascade lasers
 - Applied products of semiconductor lasers
 - Solid state lasers
 - Laser related products
-

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